BU2507AF

GENERAL DESCRIPTION

Enhanced performance, new generation, high-voltage, high-speed switching npn transistor in a plastic full-pack envelope intended for use in horizontal deflection circuits of colour television receivers and computer monitors. Features exceptional tolerance to base drive and collector current load variations resulting in a very low worst case dissipation.

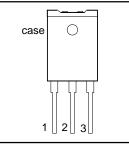
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 V$	-	1500	V
V _{CEO}	Collector-emitter voltage (open base)		-	700	V
	Collector current (DC)		-	8	A
I _{CM}	Collector current peak value		-	15	A
P _{tot}	Total power dissipation	T _{hs} ≤ 25 °C	- 1	45	W
I _{CM} P _{tot} V _{CEsat}	Collector-emitter saturation voltage	$I_{\rm C} = 4 \text{ A}; I_{\rm B} = 0.95 \text{ A}$	-	1.0	V
V _{CEsat}	Collector-emitter saturation voltage	$I_{\rm C} = 4 {\rm A}; I_{\rm B} = 0.8 {\rm A}$	- 1	5.0	V
I _{Csat}	Collector saturation current	f = 16kHz	4	-	A
t _f	Fall time	$I_{Csat} = 4 \text{ A}; f = 16 \text{kHz}$	0.25	0.5	μs

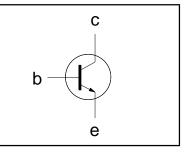
PINNING - SOT199

PIN	DESCRIPTION
1	base
2	collector
3	emitter
case	isolated

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 V$	-	1500	V
V _{CEO}	Collector-emitter voltage (open base)	52	-	700	V
I _C	Collector current (DC)		-	8	А
I _{CM}	Collector current peak value		-	15	А
I _B	Base current (DC)		-	4	А
I _{BM}	Base current peak value		-	6	А
-I _{B(AV)}	Reverse base current	average over any 20 ms period	-	100	mA
-I _{BM}	Reverse base current peak value ¹		-	5	А
	Total power dissipation	$T_{hs} \leq 25 \degree C$	-	45	W
P _{tot} T _{stg}	Storage temperature		-65	150	°C
T _j	Junction temperature		-	150	°C

¹ Turn-off current.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-hs}	Junction to heatsink	without heatsink compound	-	3.7	K/W
R _{th j-hs}	Junction to heatsink	with heatsink compound	-	2.8	K/W
R _{th j-a}	Junction to ambient	in free air	35	-	K/W

ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	Repetitive peak voltage from all three terminals to external heatsink	$R.H. \leq 65~\%$; clean and dustfree	-		2500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	22	-	pF

STATIC CHARACTERISTICS

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES}	Collector cut-off current ²	$V_{BE} = 0 V; V_{CE} = V_{CESMmax}$	-	-	1.0	mA
I _{CES}		$V_{BE} = 0 V; V_{CE} = V_{CESMmax}$ $V_{BE} = 0 V; V_{CE} = V_{CESMmax}$ $T_{i} = 125 °C$	-	-	2.0	mA
I _{EBO}	Emitter cut-off current	$V_{EB} = 7.5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	1.0	mA
V _{CEOsust}	Collector-emitter sustaining voltage	I _B = 0 A; I _C = 100 mA; L = 25 mH	700	-	-	V
BV _{EBO}	Emitter-base breakdown voltage	$I_{B} = 1 \text{ mA}$	7.5	13.5	-	V
V _{CEsat}	Collector-emitter saturation voltages	$I_{\rm C} = 4 \text{ A}; I_{\rm B} = 0.8 \text{ A}$	-	-	5.0	V
V _{BEsat}	Base-emitter saturation voltage	$I_{\rm C} = 4$ A; $I_{\rm B} = 0.8$ A	-	-	1.1	V
h _{FE}	DC current gain	I _c = 100 mA; V _{ce} = 5 V I _c = 4 A; V _{ce} = 5 V	-	17	-	
h _{FE}		$I_{C} = 4 \text{ A}; V_{CE} = 5 \text{ V}$	5.0	7.0	9.0	

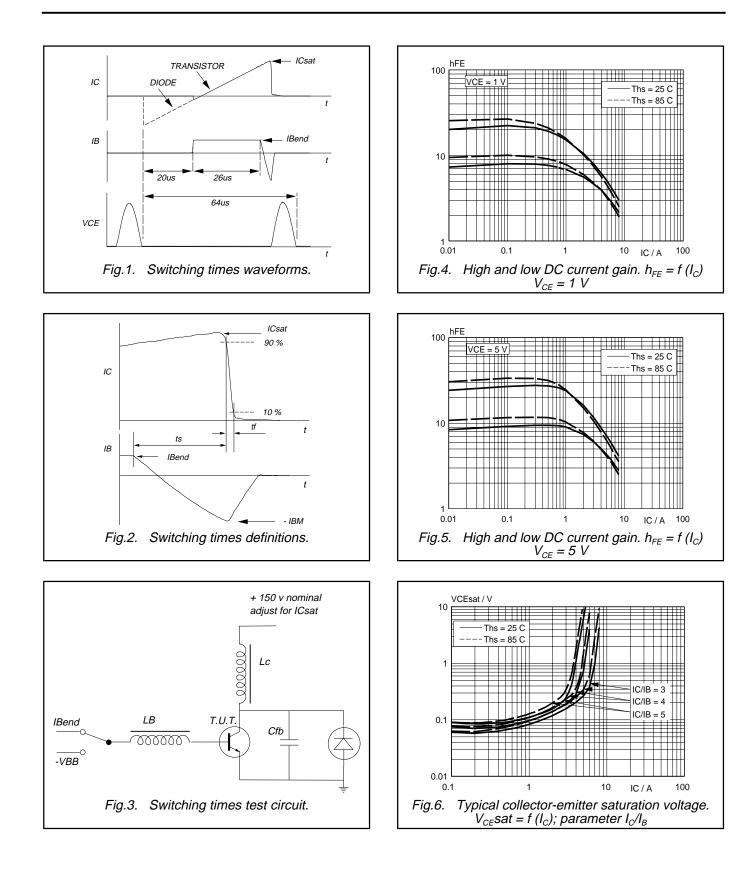
DYNAMIC CHARACTERISTICS

 T_{hs} = 25 °C unless otherwise specified

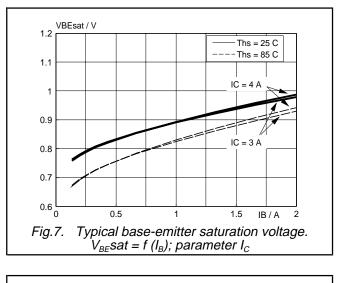
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
C _c	Collector capacitance	$I_{E} = 0 \text{ A}; V_{CB} = 10 \text{ V}; \text{ f} = 1 \text{ MHz}$	68	-	pF
t _s t _f	Switching times (16 kHz line deflection circuit) Turn-off storage time Turn-off fall time	I_{Csat} = 4 A; $I_{B(end)}$ = 0.7 A; L_{B} = 6 $\mu H;$ -V $_{BB}$ = 4 V	5.0 0.25	6.0 0.5	μs μs

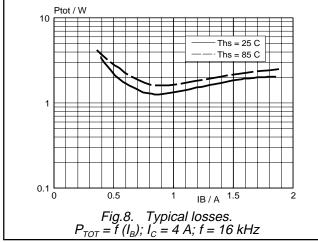
² Measured with half sine-wave voltage (curve tracer).

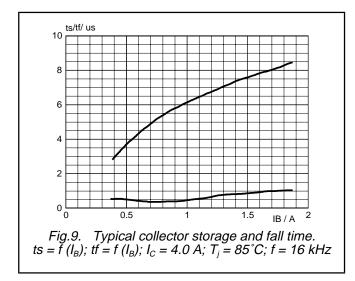
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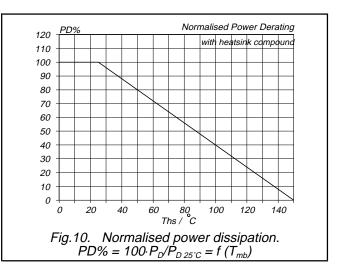


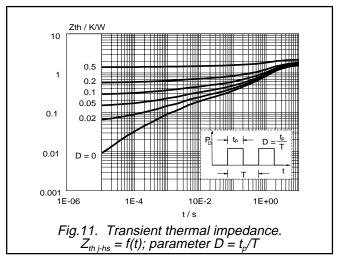
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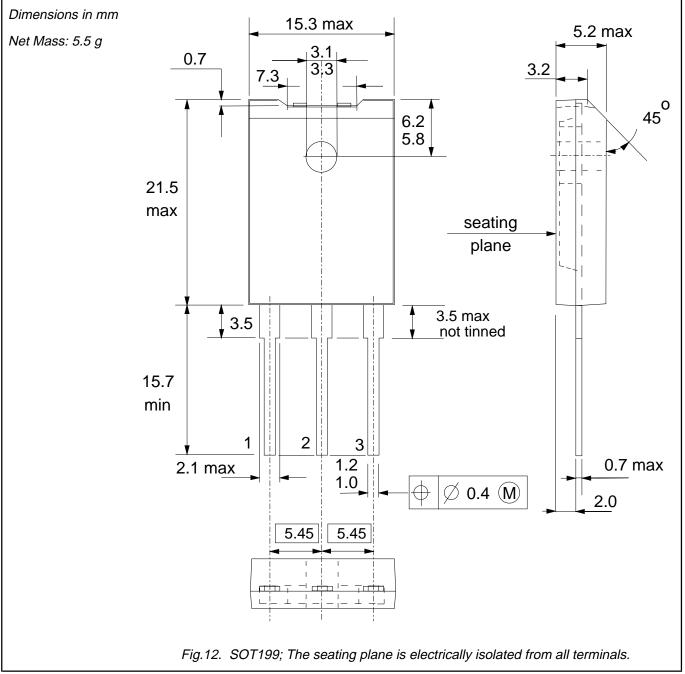




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Product specification

MECHANICAL DATA



Notes

Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status				
Objective specification	ecification This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
or more of the limiting val operation of the device at	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one ues may cause permanent damage to the device. These are stress ratings only and these or at any other conditions above those given in the Characteristics sections of plied. Exposure to limiting values for extended periods may affect device reliability.			
Application information				
Where application information is given, it is advisory and does not form part of the specification.				
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